

Device Modeling Report

COMPONENTS:
DIODE/ GENERAL PURPOSE RECTIFIER/ PROFESSIONAL
PART NUMBER: 5GLZ47A
MANUFACTURER: TOSHIBA
REMARK: TC=80C

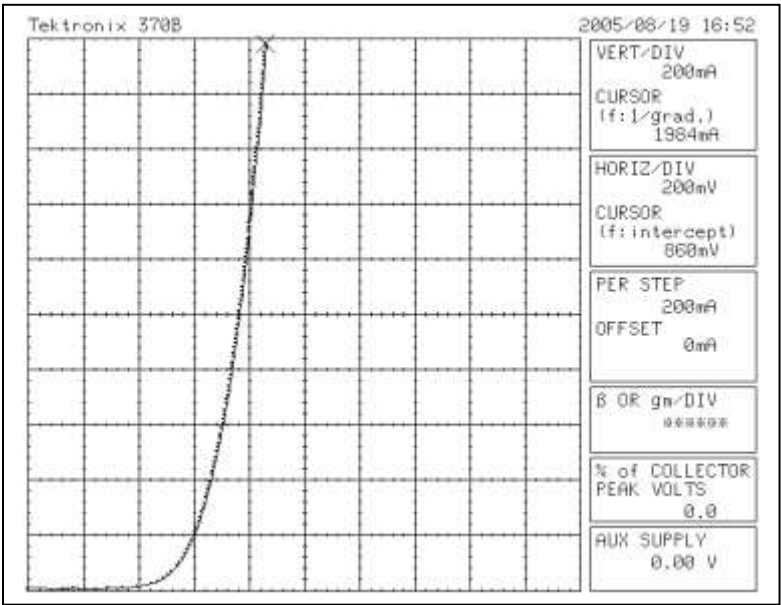


Bee Technologies Inc.

PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

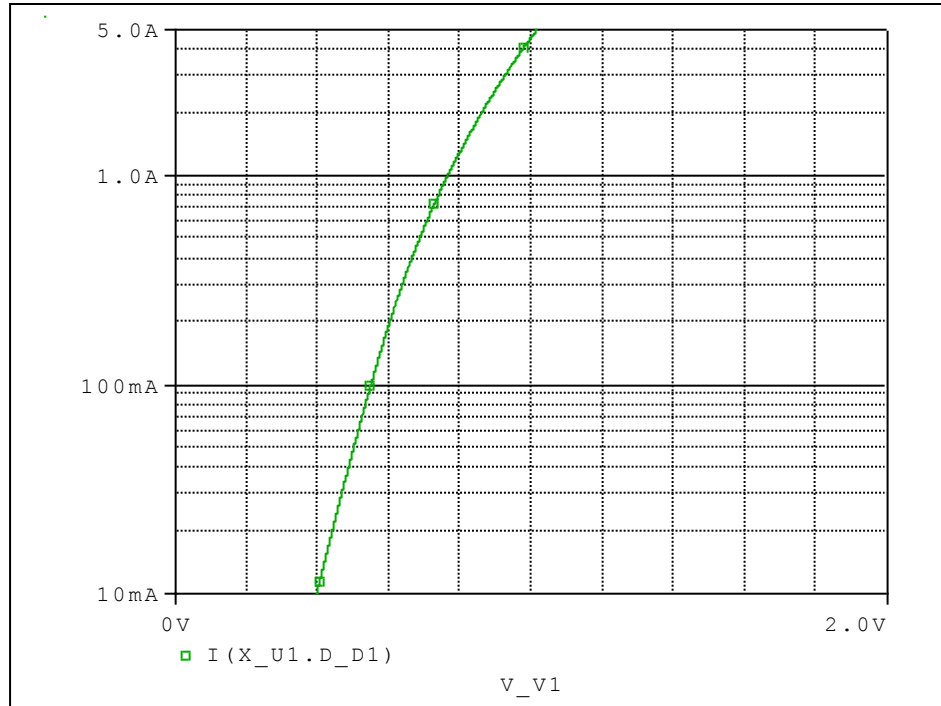
Forward Current Characteristic

Reference

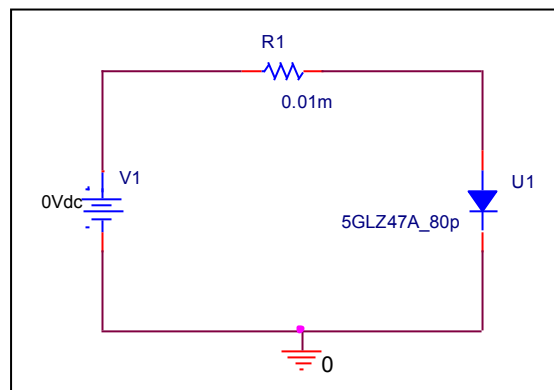


Forward Current Characteristic

Circuit Simulation Result

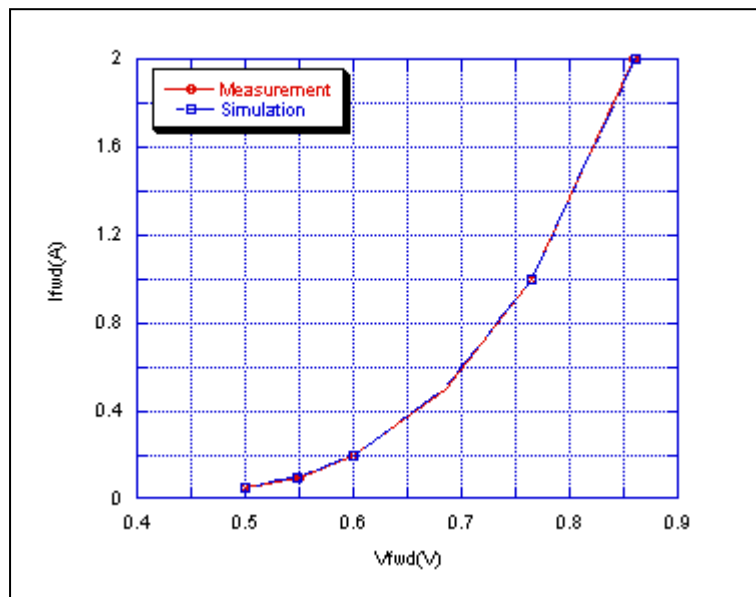


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

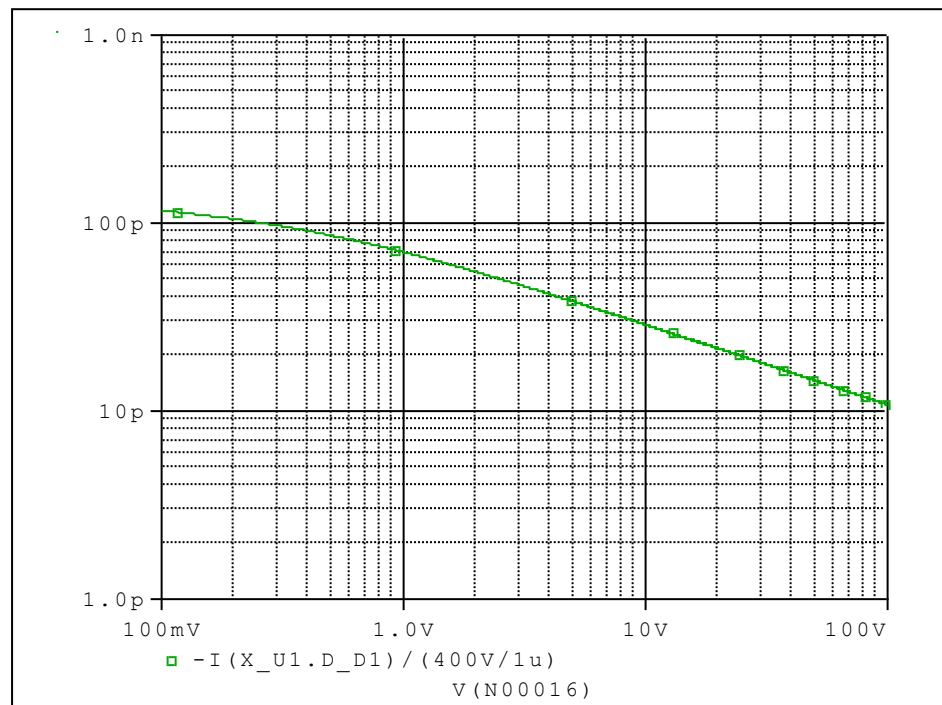


Simulation Result

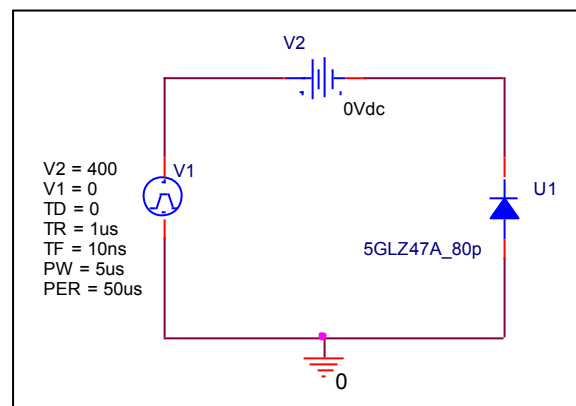
Ifwd(A)	Vfwd(V) Measurement	Vfwd(V) Simulation	%Error
0.05	0.500	0.499	0.200
0.1	0.550	0.548	0.364
0.2	0.600	0.601	-0.167
0.5	0.686	0.684	0.292
1	0.764	0.763	0.131
2	0.860	0.861	-0.116

Capacitance Characteristic

Circuit Simulation Result

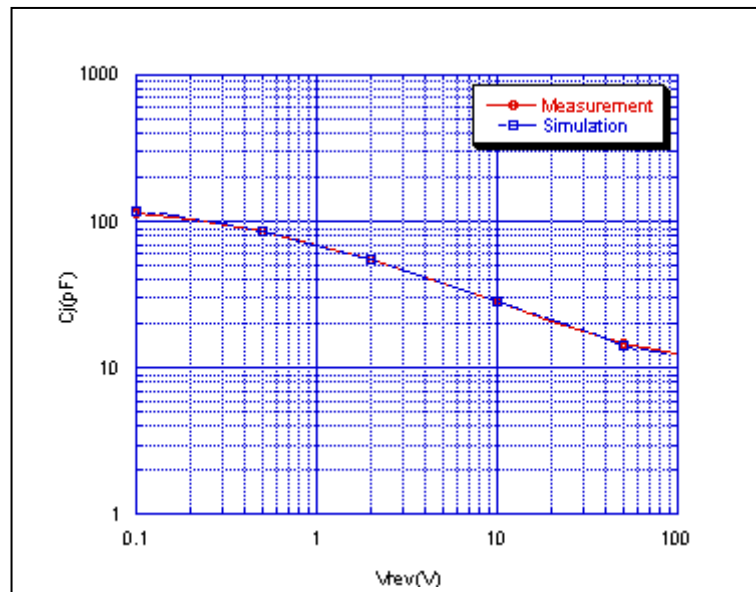


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

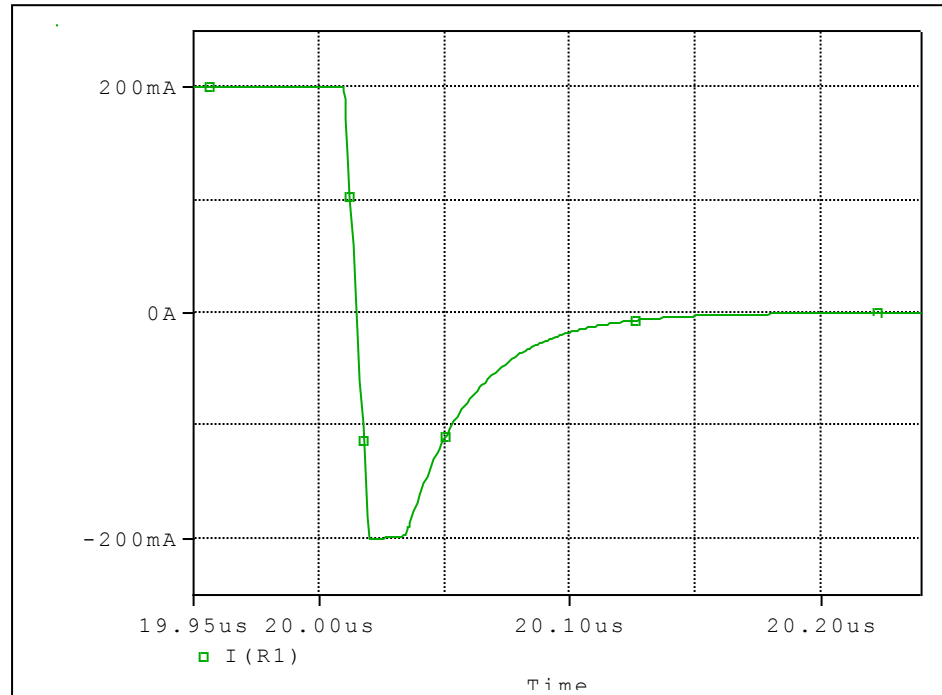


Simulation Result

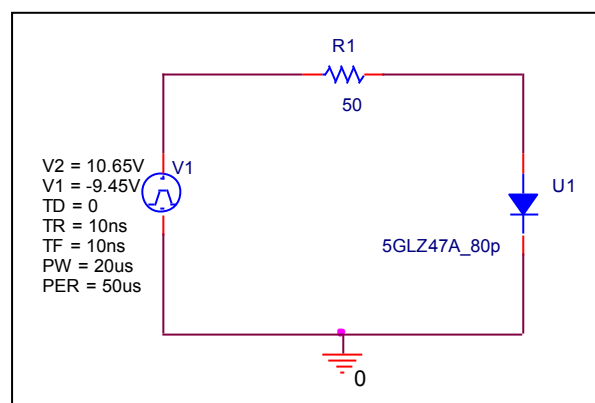
V_{rev} (V)	C_j (pF) Measurement	C_j (pF) Simulation	%Error
0	128.400	128.400	0.000
0.1	115.200	119.000	-3.299
0.2	105.200	106.400	-1.141
0.5	85.800	85.700	0.117
1	70.200	70.000	0.285
2	54.600	54.800	-0.366
5	37.400	38.300	-2.406
10	29.000	28.700	1.034
20	21.100	21.400	-1.422
50	14.600	14.500	0.685
100	12.200	11.700	4.098

Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

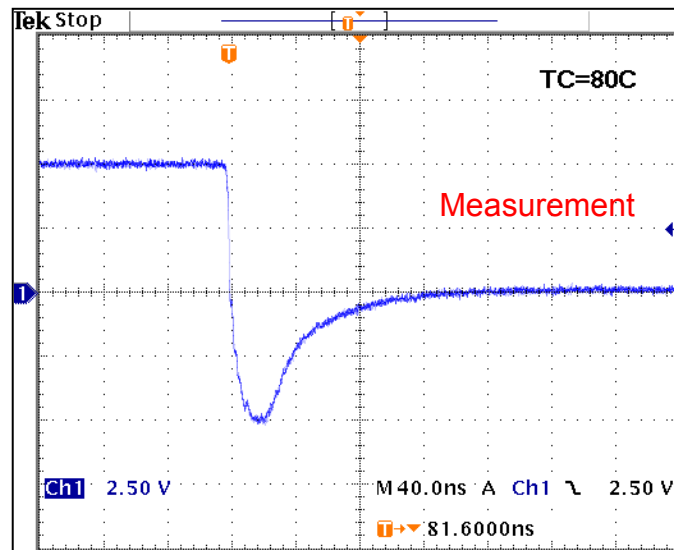


Compare Measurement vs. Simulation

	Measurement		Simulation		%Error
trj	19.20	ns	19.15	ns	0.26
trb	60.80	ns	60.90	ns	-0.16

Reverse Recovery Characteristic

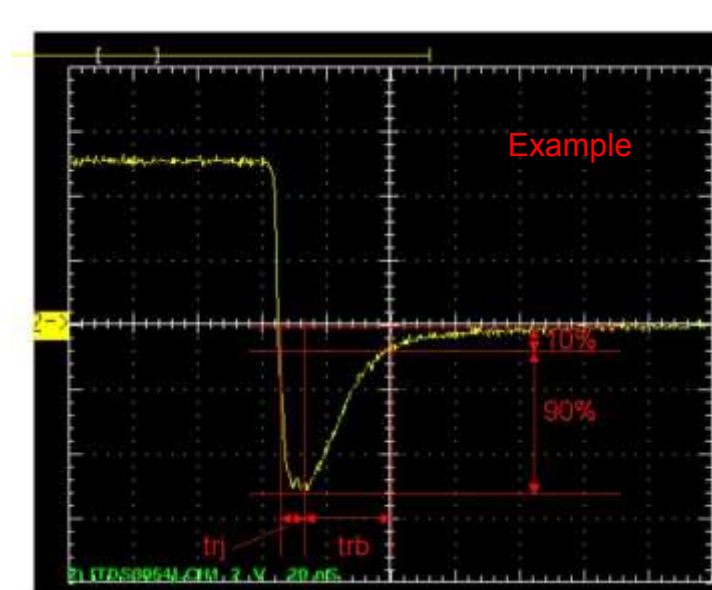
Reference



$T_{rj} = 19.2 \text{ (ns)}$

$T_{rb} = 60.8 \text{ (ns)}$

Conditions: $I_{fwd} = I_{rev} = 0.2 \text{ (A)}$, $R_I = 50$



Relation between t_{rj} and t_{rb}